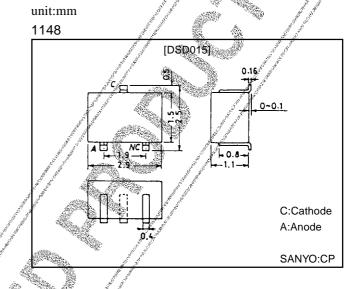


Features

- · Ideally suited for use in hybrid ICs because of very compact package.
- · High breakdown voltage.

Package Dimensions



Specifications

Absolute Maximum Ratings at Ta = 25°C

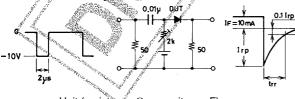
0	A S			
	Symbol	Conditions	Ratings	Unit
	^{,∕V} RM	A. M. //	350	V
	∫ ∕V _R	S. 98-39 //	300	V
a la fair a	IFSM	149	3	А
لكر تحمك	ار ما		150	mA
and the second	[↓] ĔM⊗		400	mA
and the second	P 🦉		200	mW
and the second sec			125	°C
// *	Tstg		-55 to +125	°C
		Symbol NRM VR IFSM, IQ IEM P	Symbol Conditions	Symbol Conditions Ratings /RM 350 /R 300 /IFSM 148 Ig 150 Ig 400 P 200 Tstg -55 to +125

Electrical Characteristics at $Ta = 25^{\circ}C^{\circ}$

	Parameter		Symbol 🥖	Conditions		Ratings		
	ralamotei		Symbol	Conditions	min	typ	max	Unit
Forward Voltage	Sec. Starting		٧ _F	I _F =100mA			1.0	V
Reverse Current	11	à dà	R	V _R =300V			0.5	μΑ
Interterminal Capa	citance		C C	V _R =0V, f=1MHz		4		pF
Reverse Recovery	53.2 .4		s ^{ad t} rr	$I_F=10mA$, $V_R=10V$, $R_L=50\Omega$, $I_{rr}=0.1I_{rp}$		30	200	ns

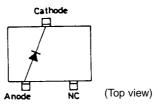
Safet and Street

Reverse Recovery Time Test Circuit



Unit (resistance:Ω, capacitance:F)

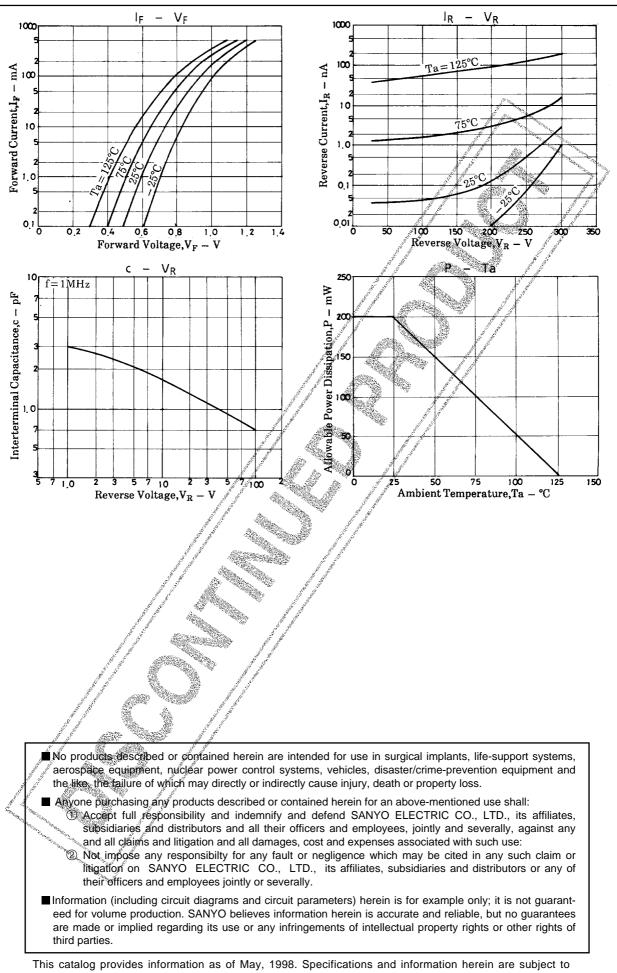
Electrical Connection



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53098HA (KT)/2150MO, TS No.3333-1/2





change without notice.